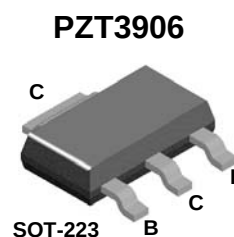
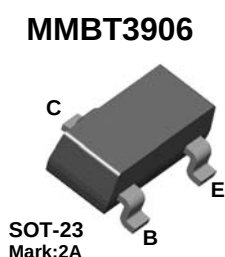


2N3906 / MMBT3906 / PZT3906

PNP General Purpose Amplifier

Features

- This device is designed for general purpose amplifier and switching applications at collector currents of 10 μ A to 100 mA.



Absolute Maximum Ratings* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	-40	V
V_{CBO}	Collector-Base Voltage	-40	V
V_{EBO}	Emitter-Base Voltage	-5.0	V
I_C	Collector Current - Continuous	-200	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.			Units
		2N3906	*MMBT3906	**PZT3906	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	$^\circ\text{C}/\text{W}$

* Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

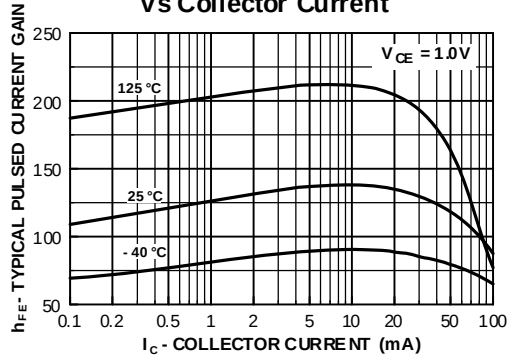
Symbol	Parameter	Test Condition	Min.	Max.	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = -1.0\text{mA}$, $I_B = 0$	-40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -10\mu\text{A}$, $I_E = 0$	-40		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}$, $I_C = 0$	-5.0		V
I_{BL}	Base Cutoff Current	$V_{CE} = -30\text{V}$, $V_{BE} = -3.0\text{V}$		-50	nA
I_{CEX}	Collector Cutoff Current	$V_{CE} = -30\text{V}$, $V_{BE} = -3.0\text{V}$		-50	nA
ON CHARACTERISTICS					
h_{FE}	DC Current Gain*	$I_C = -0.1\text{mA}$, $V_{CE} = -1.0\text{V}$ $I_C = -1.0\text{mA}$, $V_{CE} = -1.0\text{V}$ $I_C = -10\text{mA}$, $V_{CE} = -1.0\text{V}$ $I_C = -50\text{mA}$, $V_{CE} = -1.0\text{V}$ $I_C = -100\text{mA}$, $V_{CE} = -1.0\text{V}$	60 80 100 60 30	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -10\text{mA}$, $I_B = -1.0\text{mA}$ $I_C = -50\text{mA}$, $I_B = -5.0\text{mA}$		-0.25 -0.4	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -10\text{mA}$, $I_B = -1.0\text{mA}$ $I_C = -50\text{mA}$, $I_B = -5.0\text{mA}$	-0.65	-0.85 -0.95	V V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	$I_C = -10\text{mA}$, $V_{CE} = -20\text{V}$, $f = 100\text{MHz}$	250		MHz
C_{obo}	Output Capacitance	$V_{CB} = -5.0\text{V}$, $I_E = 0$, $f = 100\text{kHz}$		4.5	pF
C_{ibo}	Input Capacitance	$V_{EB} = -0.5\text{V}$, $I_C = 0$, $f = 100\text{kHz}$		10.0	pF
NF	Noise Figure	$I_C = -100\mu\text{A}$, $V_{CE} = -5.0\text{V}$, $R_S = 1.0\text{k}\Omega$, $f = 10\text{Hz}$ to 15.7kHz		4.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	$V_{CC} = -3.0\text{V}$, $V_{BE} = -0.5\text{V}$		35	ns
t_r	Rise Time	$I_C = -10\text{mA}$, $I_{B1} = -1.0\text{mA}$		35	ns
t_s	Storage Time	$V_{CC} = -3.0\text{V}$, $I_C = -10\text{mA}$,		225	ns
t_f	Fall Time	$I_{B1} = I_{B2} = -1.0\text{mA}$		75	ns

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$ **Ordering Information**

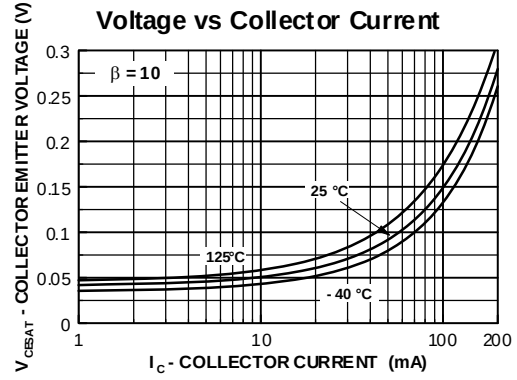
Part Number	Marking	Package	Packing Method	Pack Qty
2N3906BU	2N3906	TO-92	BULK	10000
2N3906TA	2N3906	TO-92	AMMO	2000
2N3906TAR	2N3906	TO-92	AMMO	2000
2N3906TF	2N3906	TO-92	TAPE REEL	2000
2N3906TFR	2N3906	TO-92	TAPE REEL	2000
MMBT3906	2A	SOT-23	TAPE REEL	3000
PZT3906	3906	SOT-223	TAPE REEL	2500

Typical Performance Characteristics

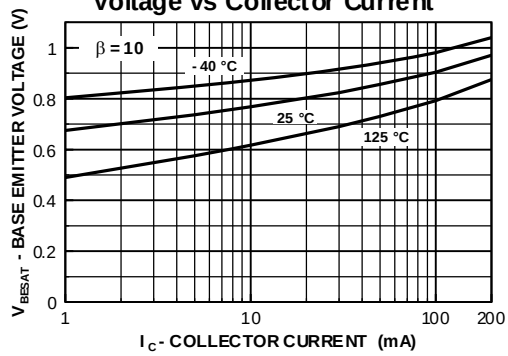
Typical Pulsed Current Gain vs Collector Current



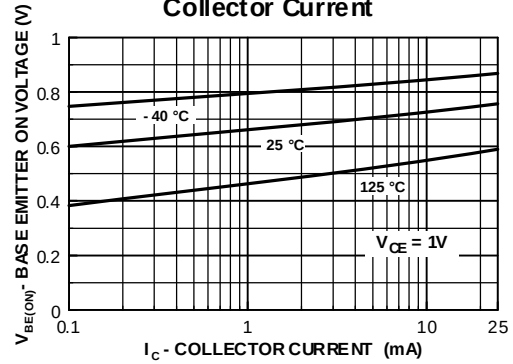
Collector-Emitter Saturation Voltage vs Collector Current



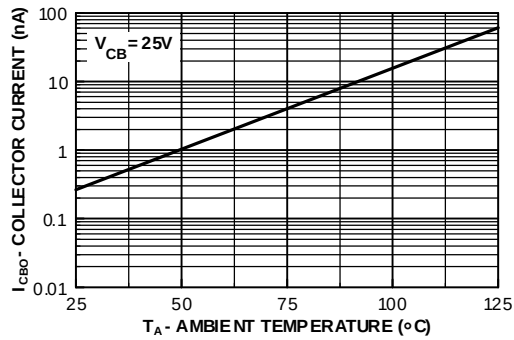
Base-Emitter Saturation Voltage vs Collector Current



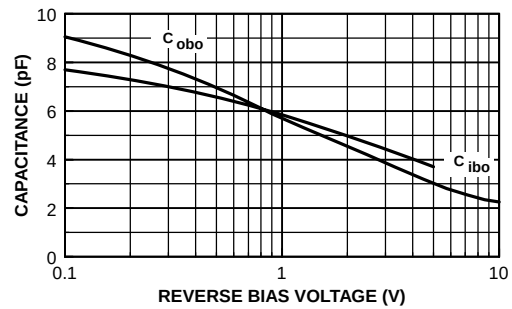
Base Emitter ON Voltage vs Collector Current



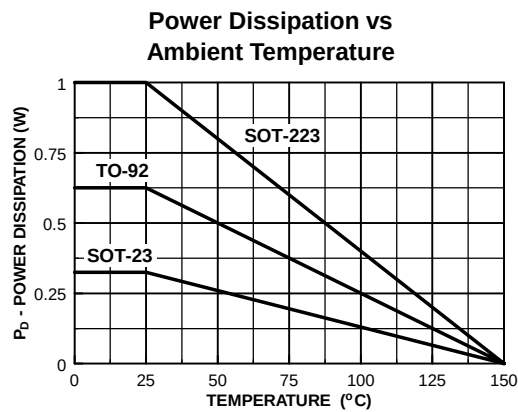
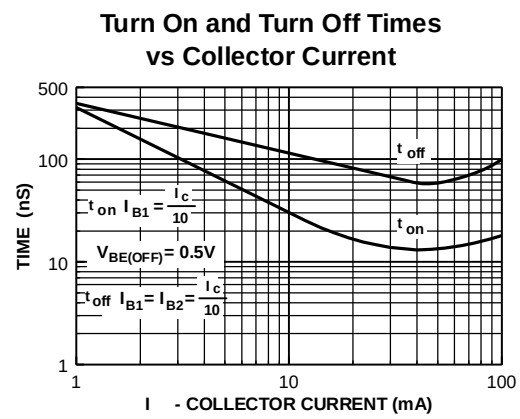
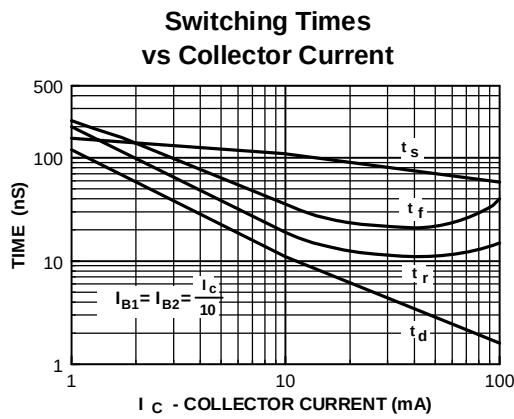
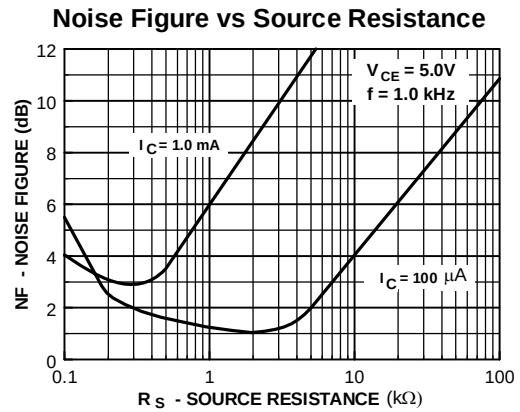
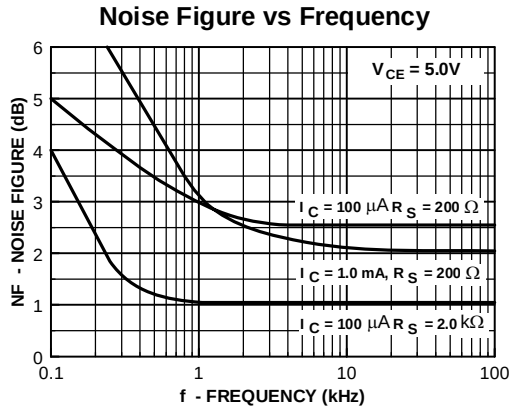
Collector-Cutoff Current vs Ambient Temperature



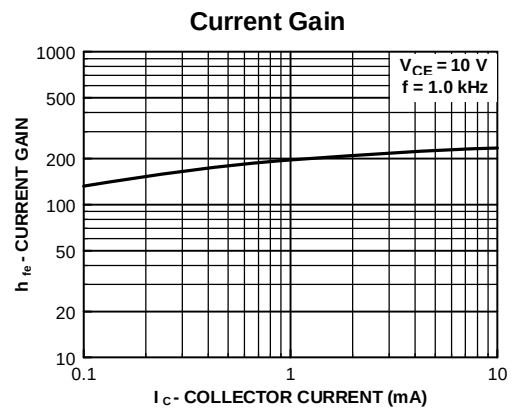
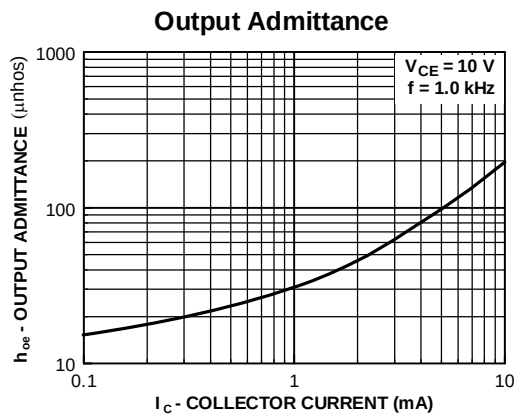
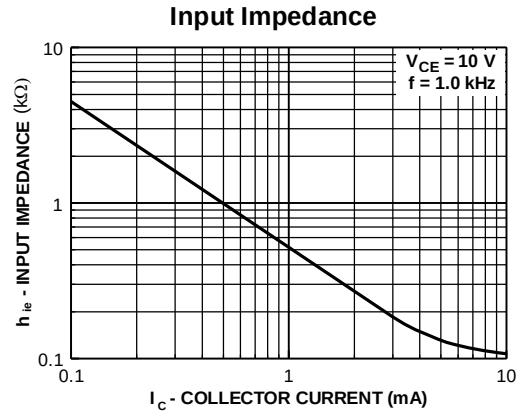
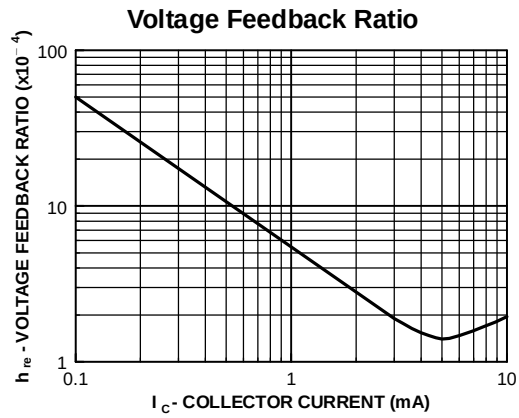
Common-Base Open Circuit Input and Output Capacitance vs Reverse Bias Voltage



Typical Performance Characteristics (continued)



Typical Performance Characteristics (continued)





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